NSN 5961-01-089-1952

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-089-1952 **Inclosure Material:** Metal **Overall Length:** 0.780 inches **Overall Diameter:** 1.900 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 7500.0 reverse voltage, peak **Current Rating Per Characteristic:** 1.00 amperes reverse current, average **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 case and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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